

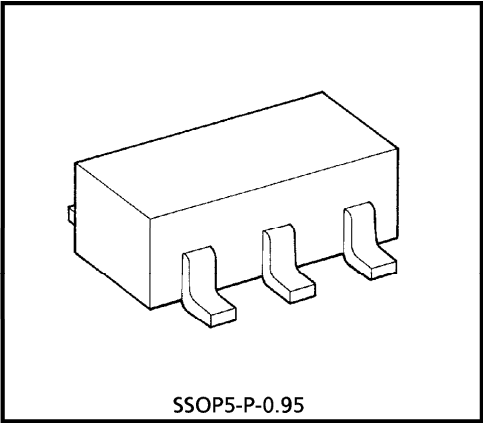
TC4SU11F

2 INPUT NAND GATE

TC4SU11F is 2 input NAND gate respectively.
The internal circuit of only basic NAND circuit without the waveform shaping inverter.
Therefore, this is suitable for the applications in liner circuits such as oscillator circuits and amplifier circuits, and this has advantage in the applications of Logical processing systems with faster operating speed.

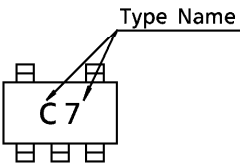
MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	V _{DD}	V _{SS} - 0.5~V _{SS} + 20	V
Input Voltage	V _{IN}	V _{SS} - 0.5~V _{DD} + 0.5	V
Output Voltage	V _{OUT}	V _{SS} - 0.5~V _{DD} + 0.5	V
DC Input Current	I _{IN}	± 10	mA
Power Dissipation	P _D	200	mW
Operating Temperature Range	T _{opr}	- 40~85	°C
Storage Temperature Range	T _{stg}	- 65~150	°C
Lead Temperature (10s)	T _L	260	°C

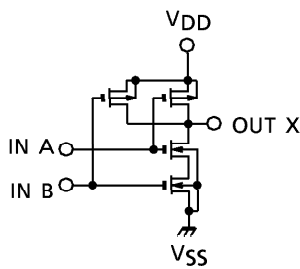


SSOP5-P-0.95
Weight : 0.016g (Typ.)

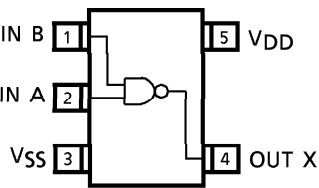
Marking



LOGIC DIAGRAM



PIN ASSIGNMENT (TOP VIEW)



RECOMMENDED OPERATING CONDITIONS ($V_{SS} = 0V$)

CHARACTERISTIC	SYMBOL		MIN.	TYP.	MAX.	UNIT
DC Supply Voltage	V_{DD}	—	3	—	18	V
Input Voltage	V_{IN}	—	0	—	V_{DD}	V

STATIC ELECTRICAL CHARACTERISTICS ($V_{SS} = 0V$)

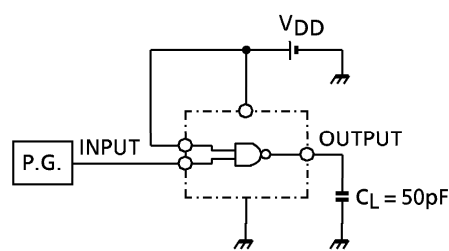
CHARACTERISTIC	SYM-BOL	TEST CONDITION	V_{DD} (V)	- 40°C		25°C			85°C		UNIT
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Output Voltage	V_{OH}	$ I_{OUT} < 1\mu A$ $V_{IN} = V_{SS}$	5	4.95	—	4.95	5.00	—	4.95	—	V
			10	9.95	—	9.95	10.00	—	9.95	—	
			15	14.95	—	14.95	15.00	—	14.95	—	
Low-Level Output Voltage	V_{OL}	$ I_{OUT} < 1\mu A$ $V_{IN} = V_{DD}$	5	—	0.05	—	0.00	0.05	—	0.05	V
			10	—	0.05	—	0.00	0.05	—	0.05	
			15	—	0.05	—	0.00	0.05	—	0.05	
Output High Current	I_{OH}	$V_{OH} = 4.6V$	5	-0.61	—	-0.51	-1.0	—	-0.42	—	mA
		$V_{OH} = 2.5V$	5	-2.5	—	-2.1	-4.0	—	-1.7	—	
		$V_{OH} = 9.5V$	10	-1.5	—	-1.3	-2.2	—	-1.1	—	
		$V_{OH} = 13.5V$	15	-4.0	—	-3.4	-9.0	—	-2.8	—	
Output Low Current	I_{OL}	$V_{IN} = V_{SS}, V_{DD}$									mA
		$V_{OL} = 0.4V$	5	0.61	—	0.51	1.2	—	0.42	—	
		$V_{OL} = 0.5V$	10	1.5	—	1.3	3.2	—	1.1	—	
		$V_{OL} = 1.5V$	15	4.0	—	3.4	12.0	—	2.8	—	
Input High Voltage	V_{IH}	$V_{IN} = V_{DD}$									V
		$V_{OUT} = 0.5V$	5	4.0	—	4.0	3.0	—	4.0	—	
		$V_{OUT} = 1.0V$	10	8.0	—	8.0	6.5	—	8.0	—	
		$V_{OUT} = 1.5V$	15	12.0	—	12.0	9.5	—	12.0	—	
Input Low Voltage	V_{IL}	$ I_{OUT} < 1\mu A$									V
		$V_{OUT} = 4.5V$	5	—	1.0	—	2.0	1.0	—	1.0	
		$V_{OUT} = 9.0V$	10	—	2.0	—	3.5	2.0	—	2.0	
		$V_{OUT} = 13.5V$	15	—	3.0	—	5.5	3.0	—	3.0	
Input Current	H Level	I_{IH}	$V_{IH} = 18V$	18	—	0.1	—	10^{-5}	0.1	—	μA
	L Level	I_{IL}	$V_{IL} = 0V$	18	—	-0.1	—	-10^{-5}	-0.1	—	
Quiescent Device Current	I_{DD}	$V_{IN} = V_{SS}, V_{DD}$	5	—	0.25	—	0.001	0.25	—	7.5	μA
			10	—	0.5	—	0.001	0.5	—	15	
			15	—	1.0	—	0.002	1.0	—	30	

DYNAMIC ELECTRICAL CHARACTERISTICS (Ta = 25°C, VSS = 0V, CL = 50pF)

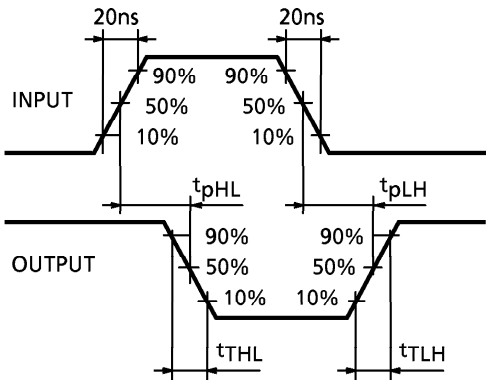
CHARACTERISTIC	SYMBOL	TEST CONDITION	VDD (V)	MIN.	TYP.	MAX.	UNIT
Output Transition Time (Low to High)	tTLH	—	5	—	70	200	ns
			10	—	35	100	
			15	—	30	80	
Output Transition Time (High to Low)	tTHL	—	5	—	60	200	ns
			10	—	25	100	
			15	—	20	80	
Propagation Delay Time	tpLH	—	5	—	50	110	ns
			10	—	28	60	
			15	—	22	50	
Propagation Delay Time	tpHL	—	5	—	50	110	ns
			10	—	28	60	
			15	—	22	50	
Input Capacitance	CIN	—		—	5	7.5	pF

CIRCUIT AND WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS

CIRCUIT



WAVEFORM



PACKAGE DIMENSIONS
SSOP5-P-0.95

Unit : mm



Weight : 0.016g (Typ.)

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000707EBA

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